

**MNT 503**  
**Nanoscale Synthesis and Characterization**  
**(2024-2025 Spring)**  
Assignment 1

- 1- Which one of the followings is an important issue in fabricating of nanostructures?
- ☐ dimension
  - ☐ morphology
  - ☐ structure
  - ☐ composition
  - ☐ all of them
- 2- Choose the odd one out about bottom-up synthesis technique.
- ☐ fabrication is relatively expensive
  - ☐ it starts with atoms or molecules
  - ☐ physical forces are operative in building nanostructures
  - ☐ formation of nanoparticles from colloidal solution is a bottom-up technique
  - ☐ physical vapor deposition technique uses bottom-up approach
- 3- Choose the false statement about thin film deposition techniques
- ☐ deposition is achieved by mechanical, chemical or high vacuum (physical) evaporation methods
  - ☐ they are bottom-up technology
  - ☐ vapor deposition methods are two kinds: physical and chemical vapor deposition methods
  - ☐ only micrometer thick coatings can be produced
  - ☐ emission, transport and condensation of particles are the common steps of deposition techniques
- 4- Which one of the followings is true about PVD?
- ☐ it is a gas phase deposition technique and carried out under high vacuum level
  - ☐ as vacuum level increases (small vacuum number) more dense films are obtained since mean free path ( $\lambda$ ) increases
  - ☐ both thermal and e-beam methods are classified as evaporation methods
  - ☐ common sputter methods are DC, RF and magnetron sputtering methods
  - ☐ all of them
- 5- Which one of the followings is not related to sputtering technique
- ☐ DC sputtering is used only for metals
  - ☐ atoms are ejected from target material by impact of energetic ions
  - ☐ all of the sputtering techniques make use of Ar ions
  - ☐ ceramic deposition is possible by RF sputtering
  - ☐ deposition rate in sputtering is relatively low compared to thermal PVD methods
- 6- Thermal PVD techniques can be used to deposit dielectrics on a substrate.....**T F**
- 7- In magnetron sputtering techniques, magnetic field is used to trap electrons to be used in ionization of argon.....**T F**
- 8- Oblique angle deposition technique is a PVD technique in which angle of incidence is lower than  $70^\circ$  .....**T F**